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Docket No.: M4065.0761/P761
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Chandra Mouli et al.

Application No.: 10/602,721

Confirmation No.: 9931

Filed: June 25, 2003

Art Unit: 2815

For: REDUCED BARRIER
PHOTODIODE/GATE DEVICE
STRUCTURE FOR HIGH EFFICIENCY
CHARGE TRANSFER AND REDUCED
LAG AND METHOD OF FORMATION

Examiner: E. Lee

RESPONSE TO RESTRICTION REQUIREMENT

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the restriction requirement set forth in the Office Action mailed August 24, 2004 (Paper No. Mail Date 20040819), Applicants hereby elect Group I claims 1-37 for continued examination without traverse.

The Examiner has required restriction between the following:

Group I – Claims 1-37, drawn to a semiconductor device; and

Group II – Claims 38-58, drawn to a method of making a semiconductor device.

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Dated: August 31, 2004

Respectfully submitted,

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